Phase stability and mechanical property trends for MAB phases by high-throughput ab initio calculations

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ABSTRACT

MAB phases (MABs) are atomically-thin laminates of ceramic/metallic-like layers, having made a breakthrough in the development of 2D materials. Though theoretically offering a vast chemical and phase space, relatively few MABs have yet been synthesised. To guide experiments, we perform a systematic high-throughput *ab initio* screening of MABs that combine group 4–7 transition metals (M); AI, Si, Ga, Ge, or In (A); and boron (B) focusing on their phase stability trends and mechanical properties. Considering the 1:1:1, 2:1:1, 2:1:2, 3:1:2, 3:1:3, and 3:1:4 M:A:B ratios and 10 phase prototypes, possible stabilisation of a single-phase compound for each elemental combination is assessed through formation energy spectra of the competing mechanically and dynamically stable MABs. Based on the volumetric proximity of energetically-close phases, we identify systems in which volume-changing deformations may facilitate transformation toughening. Subsequently, chemistryand phase-structure-related trends in the elastic stiffness and ductility are predicted using elastic-constants-based descriptors. The analysis of directional Cauchy pressures and Young's moduli allows comparing mechanical response parallel and normal to M–B/A layers. Among the suggested most promising MABs are Nb₃AlB₄, Cr₂SiB₂, Mn₂SiB₂ or the already synthesised MoAlB.

Keywords: MAB phase; Ab initio; Phase stability; Elastic constants; Ductility

1 Introduction

MAB phases (MABs) are atomically-laminated borides in which hard ceramic-like transition metal M–B layers alternate with relatively softer metallic-like mono- or bilayers of an A-element (typically Al, Si, Ga or In)^{1,2}. Though discovered already in the 60s³, MABs have recently made a breakthrough in the development of 2D materials for new-generation nanodevices^{4–6}. Offering an interesting combination of mechanical, magnetocaloric, and catalytic properties, high-temperature oxidation resistance, as well as damage and radiation tolerance, MABs are prominent candidates for applications in the fields of protective and wear-resistant coatings, magnetic cooling, electrocatalysis or electrochemical sensing, or radiation shielding^{1,7–9}.

With typical formula $M_{n+1}AB_{2n}$ $(n = \{1,2,3\})^{10}$ and possible structures with hexagonal² or orthorhombic¹ symmetry, MABs theoretically provide a vast chemical and phase space. However, relatively few material systems have been achieved experimentally: mostly bulk polycrystals (Ti₂InB₂², Cr₂AlB₂¹¹⁻¹³, Cr₃AlB₄^{12,13}, Cr₄AlB₆¹³, MoAlB^{9,14}, WAlB^{9,15}, Fe₂AlB₂¹⁶, Mn₂AlB₂¹⁷), and only one thin film (MoAlB^{18–20}). Thus, further development of both bulk and thin film MAB phases calls for a systematic computational screening across a relevant subspace of the periodic table, in particular, predicting trends in the phase stability and structure–property relationships for various M and A combinations.

In terms of phase stability predictions, solid work has already been done using the *ab initio* density functional theory (DFT) framework (see, e.g., Refs.^{7, 10, 21–25}), or machine-learning based approaches^{26, 27}. In particular, Khazaei et al.²² studied stability of the orthorhombic M₂AlB₂, MAlB, M_3AlB_4 , and M_4AlB_6 systems with M from the group 3–6 transition metals, considering the decomposition into competing M-B, M-Al, and M-Al-B compounds. Siriwardane et al.⁷ suggested that stability of a MAB phase for a given M decreases for A changing from Al \rightarrow Ga \rightarrow In \rightarrow Tl, i.e., with increasing atomic number of the A element. This observation was correlated with increased M-A and B-A bond lengths, causing a decreased ionicity. Later, Carlsson et al.¹⁰ screened orthorhombic and hexagonal MAB, M2AB2, M3AB4, M4AB4, and M₄AB₆ phases with M from the group 3–6 transition metals or Mn, Fe, Co, and $A = \{AI, Ga, In\}$, confirming thermodynamic stability of 7 previously synthesised MABs, predicting 3 additional ones to be stable and 23 nearly stable. Furthermore, the authors hypothesised on preferential orthorhombic/hexagonal symmetry for MAB phases containing Al and {Ga, In}, respectively.

Most *ab initio* investigations have been directed to identification of new stable MABs, while only few aimed on systematic predictions of materials' properties and their relationships to phase prototypes and/or elemental composition^{27–30}. For purposes of this work, we focus on studies addressing mechanical behaviour^{28,29,31–33}. Within the DFT framework, this is typically realised by calculating the elastic constants (C_{ij}) and deriving phenomenological strength and ductility indicators: the Young's modulus, shear-to-bulk modulus ratio, or Cauchy pressure (widely accepted trend-givers in the family of ceramics^{34–38}). Employing C_{ij} -based indicators, Liu et al.²⁹ proposed TcAlB, NbAlB, WAlB, Tc₂AlB₂, Co₂AlB₂, and Ni₂AlB₂ to be the most ductile and Mo₂AlB₂ with W₂AlB₂ to be the stiffest MABs of the MAB and M₂AB₂ phase prototypes, considering M from the group 3–5 transition metals and A=AI. Going beyond calculations of elastic constants, Dai et al.³³ modelled (0 K) shear deformation of $(CrB_2)_nCrAI$, $n = \{1, 2, 3\}$, suggesting that tiltable B–A–B bonds can release shear strain in weaker A layers, hence, contribute to high fracture toughness and damage tolerance.

Experimental investigations on MABs' mechanical response have most often concerned Young's modulus measurements (e.g., MoAlB^{18,19} and Mn₂AlB₂¹⁷) whereas toughness-related quantities have been significantly less researched. For example, Fe₂AlB₂³⁹ exhibited $K_{1C} = 5.4 \pm$ 0.2 MPa \sqrt{m} , which exceeds typical values for transition metal diborides^{40–42}). Recently, crack deflection and crack healing behaviour have been reported for MoAlB^{43,44} and Fe₂AlB₂⁴⁵, further motivating the need for theory-based understanding of MABs' mechanical response in relation to their chemistry and phase structure.

Our study uses high-throughput DFT calculations to map phase stability trends, structural and mechanical properties of MAB phases containing group 4–7 transition metals, M = (Ti,In, Si, Ge), and boron (B). For each elemental combination, 10 phase prototypes with various M:A:B ratios are considered. These include experimentally known MAB and MAX (X=C, N) phases^{1, 2, 46}, or are inspired by common transition metal (di)boride structures, exhibiting intrinsically layered character but not yet regarded as possible MAB structures. Our initial screening concerns formation energy, mechanical, and dynamical stability calculations, identification of the most favourable structure, and prediction of a single-phase MABs synthesisability. For systems passing our stability criteria, chemistry- and phase-structure-related trends in elastic stiffness and ductility are predicted, including both the polycrystalline approximates and directional values parallel and normal to the metal/ceramic layers. Finally, the most promising candidates for the synthesis of novel MABs are suggested.

2 Methods

Density Functional Theory (DFT) calculations were performed using the Vienna Ab-initio Simulation Package (VASP)^{47,48} together with the projector augmented planewave (PAW) method⁴⁹ and the Perdew-Burke-Ernzerhof (PBE) generalised gradient approximation⁵⁰. Following convergence tests, the plane-wave cutoff energy was set to 600 eV and the Γ -centred *k*-point mesh of the Brillouin-zone was automatically generated with a length parameter (R_k) of 60 Å (i.e., *k*-points separated by 1/60 Å⁻¹ along each *b* vector).

In total 60 atomically-laminated M–A–B systems were modelled, including all combinations of M = (Ti, Zr, Hf; V,Nb, Ta; Cr, Mo, W; Mn, Tc, Re), A = (Al, Ga, In, Si, Ge) and boron (B). For each elemental combination, we considered the 1:1:1, 2:1:1, 2:1:2, 3:1:2, 3:1:3, and 3:1:4 ratio between M, A, and boron, and 10 MAB phase prototypes given below and schematically depicted in Fig. 1 (the thereby established notation will be used throughout this work):

- For the **1:1:1 chemistry**: **MAB** (orthorhombic with a space group (s.g.) *Cmcm*; a 12-atom simulation cell).
- For the **2:1:1 chemistry**: **M**₂**AB** (hexagonal with a s.g. $P6_3/mmc$; an 8-atom simulation cell).
- For the **2:1:2 chemistry**: M_2AB_2 (orthorhombic with a s.g. *Cmmm*; a 10-atom simulation cell), α -M₂AB₂ (hexagonal with a s.g. $P\overline{6}m2$; a 10-atom simulation cell), ω -M₂AB₂ (hexagonal with a s.g. P6₃/mmc, a 20-atom simulation cell), and ω '-M₂AB₂ (hexagonal with a s.g. P6₃/mmc, a 20-atom simulation cell), γ -M₂AB₂ (hexagonal with a s.g. P6₃/mmc, a 10-atom simulation cell).
- For the **3:1:2 chemistry**: **M**₃**AB**₂ (hexagonal with a s.g. $P6_3/mmc$; a 12-atom simulation cell).
- For the **3:1:3 chemistry**: **M**₃**AB**₃ (orthorhombic with a s.g. Pnma; a 14-atom simulation cell).
- For the **3:1:4 chemistry**: **M**₃**AB**₄ (orthorhombic with a s.g. Pmmm; an 8-atom simulation cell).

The above-described phase prototypes were fully relaxed for all combinations of M and A elements (in total 600 MABs), until forces on ions did not exceed 0.005 eV/Å and total energies were converged up to 10^{-5} eV/supercell. Cr- and Mn-based MAB phases have been considered in their nonmagnetic state. Subsequently, relative chemical stability was estimated by the energy of formation

$$E_f = \frac{1}{\sum_s n_s} \left(E_{\text{tot}} - \sum_s n_s \mu_s \right) \,, \tag{1}$$

where E_{tot} is the total energy of the simulation cell (from the last ionic step of a structure relaxation), n_s and μ_s are the number of atoms and the chemical potential, respectively, of a species *s*. Chemical potentials, μ_s , were conventionally set to the total energy per atom of the ground-state structure for the respective element, from Material's project⁵⁵ that is fcc-Al; bcc-V, -Nb, -Ta, -Cr, -Mo, -W, -Mn; diamond-Si, -Ge; tetragonal-In; orthorhombic-Ga; rhomboedral-B; and hcp-Ti, -Zr, -Hf, -Tc, -Re.

The stress-strain method^{56–58} was used to calculate fourth order elasticity tensors (according to Hooke's law), which were projected onto symmetric 6×6 matrices of elastic constants, C_{ij} , using the Voigt notation. Positive definiteness of the C_{ij} matrix was verified in order to determine mechanical stability of the corresponding structure⁵⁹. For mechanically stable MABs, their dynamical stability was assessed based on the corresponding phonon spectra: by checking for no imaginary phonon modes (i.e. non-zero phonon density of states only in the positive frequency region). The phonon spectra were obtained with the aid of the Phonopy package⁶⁰, using the finite displacement method with the default displacement of 0.01 Å and $2 \times 2 \times 2$ replicas of the fully relaxed MAB structures (supercells with 64–160 atoms). The supercells size

	a) MAB	b) M ₂ AB ₂	c) M ₃ AB ₄	d) M ₂ AB	e) M ₃ AB ₂
[100]					
[F0] [010]					
	f) α-Μ ₂ ΑΒ ₂	g) ω-Μ ₂ ΑΒ ₂	h) ω'-Μ ₂ ΑΕ	² i) γ-Μ ₂ ΑΒ ₂	j) M ₃ AB ₃
5 [100]					
[010]	00000 00000 00000 00000 00000 00000			0 0 0 0 0 +++++++++++++++++++++++++++++	

Figure 1. Snapshots of the here considered MAB phase prototypes. (a-c) The MAB, M₂AB₂, M₃AB₄ are known MAB phase prototypes¹ experimentally achieved for, e.g., MoAlB¹⁸, $Mn_2AlB_2^{17}$, and $Cr_3AlB_4^{12,13}$. (d–e) The M_2AB and M_3AB_2 are experimentally known MAX (X = C, N) phase prototypes⁴⁶, where the M2AB structure has been considered for MABs in a recent DFT study⁵¹. (f–j) The α -M₂AB₂, ω -M₂AB₂, ω '-M₂AB₂, γ -M₂AB₂, and M3AB3 are hand-designed based on common structures of transition metal borides (TMBs). The α -M₂AB₂ is based on the hexagonal α -AlB₂ type phase (*P6/mmm*; typical for the group 4–6 TMB_2s^{52}) and has been reported for a bulk Ti_2InB_2 MAB phase². The ω -M₂AB₂, ω '-M₂AB₂, and γ -M₂AB₂ are based on the ω -WB₂ type phase (P6₃/mmc; ABBA stacking) and the γ -ReB₂ type phase (P6₃/mmc; BABA stacking), see Ref.⁵³. The difference between ω -M₂AB₂ and ω '-M₂AB₂ is that in the former (latter), Al replaces the flat (puckered) B sheets while the puckered (flat) sheets remain B and form the ceramic M-B layer. The M₃AB₃ prototype is based on the structure of TiB (Pnma)^{54,55}. Other structures of common boride-based ceramics (e.g., Ti3B4 and Ti2B) inspired hypothetical phase prototypes of additional MABs, however, were found irrelevant due to their high formation energies, thus excluded.

effects have been tested for several cases, indicating that the chosen supercells are sufficient to verify dynamical stability.

The C_{ij} matrices of MABs fulfilling conditions for mechanical and dynamical stability were further post-processed to estimate mechanical properties. Imposing the macroscopic symmetry, the matrices were projected on those of a hexagonal or an orthorhombic system, yielding 5 and 9 independent elastic constants, respectively (C_{11} , C_{33} , C_{12} , C_{13} , C_{44} for the hexagonal symmetry, and additional C_{22} , C_{23} , and C_{55} for the orthorhombic symmetry). The polycrystalline Young's modulus, E = 9BG/(3B+G) was calculated using Hill's average of the bulk, B, and shear modulus, $G^{61,62}$. The polycrystalline Poisson's ratio, v, and the directional Young's moduli, $E^{(001)}$, (3.1b) For a given M, Al-containing (In-containing) MABs $E^{(010)}$, and $E^{(100)}$, were calculated following Ref.⁶¹. Conse-

quently, the out-of-plane and the in-plane Young's moduli, i.e., normal and parallel to the metal/ceramic layers, respectively, were calculated as

$$E^{\perp} = E^{\langle 001 \rangle} , \qquad (2)$$

$$E^{\parallel} = \frac{1}{2} \left(E^{\langle 010 \rangle} + E^{\langle 100 \rangle} \right) \,. \tag{3}$$

3 Results and discussion

3.1 Stability trends

The searched chemical and phase space of hypothetical MAB phases contains all combinations of the group 4-7 transition metals (M elements) with Al, Si, Ga, Ge or In (A elements) and 10 phase prototypes (Fig. 1) for each elemental combination. Though Tc-based MABs have expectably low appeal for applications⁶³, they are included for completeness. Our first aim is predicting stability trends, preferential phase prototypes, and energetically-close competing MABs.

The energy of formation, E_f , serves as a basic chemical stability indicator, allowing to pre-select hypothetically (meta)stable MABs further tested for stability with respect to "small" elastic deformations and phonon vibrations, i.e., mechanical and dynamical stability. For each (M, A) combination, we identify (i) the lowest-energy phase, and (ii) energetically-close phases, i.e., within an energy threshold, E_f^{thr} , from the lowest-energy phase (here $E_f^{\text{thr}} := 0.25 \text{ eV/at.}$). For thereby selected MABs, we verify positive definiteness of the corresponding elastic constants matrix (mechanical stability condition⁵⁹) and the absence of imaginary phonon modes in the phonon spectra (dynamical stability condition). Note that MABs passing these stability conditions may be still metastable against the decomposition to any competing binary or ternary non-MAB compounds^{10,22} not considered in this work.

The predicted E_f trends are depicted in Fig. 2. Out of all hypothetical MABs (total 600), about 50% (317 MABs) fulfil the above selection criteria (energetic, mechanical and dynamical stability), and are visualised by coloured symbols. Together with the analysis of the corresponding structural properties—per-atom volumes, V_{per-at.} (Suppl. Fig. S1), and densities, ρ (Suppl. Fig. S2)—results in Fig. 2 lead to the following observations:

- (3.1a) Trends in the energetic (E_f) stability are mainly driven by M. Typically, the MABs' formation energy increases for M from the group $4 \rightarrow 5 \rightarrow 6 \rightarrow 7$. Exemplarily, E_f of the M₂AlB₂ phase gradually increases from -0.93 to -0.41 eV/at. for M changing as Ti \rightarrow V \rightarrow Cr \rightarrow Mn. Generally, the E_f increase is accompanied by the volume $(V_{per-at.})$ decrease and the density (ρ) increase. Changing the M's period (4 \rightarrow 5 \rightarrow 6) has a relatively minor effect on E_f , $V_{\text{per-at.}}$, and ρ .
- typically exhibit the lowest (highest) E_f among the

here-considered phase prototypes. In-containing MABs also show the highest volume and the lowest density, possibly due to the large atomic radius of In (compared to Al, Ga, Si, and Ge), which is closer to that of M elements (see the atomic difference ratio analysis in Suppl. Fig. S3). Most often, E_f increases for A changing as Al \rightarrow Si \rightarrow Ga \rightarrow Ge \rightarrow In. The choice of A more significantly impacts stability for MABs that contain M from groups 6–7 (compared with M from groups 4–5). There are no stable MABs combining Re and In.

- (3.1c) The M element's group also notably influences which phase prototypes are energetically favourable and how many energetically-close MABs exists. The M₃AB₄ prototype always yields the lowest volume and the highest density, while the M₂AB and M₃AB₂ are typically the least dense.
 - For M from the group 4 (= Ti, Zr, Hf), the lowestenergy MABs are M₃AB₄ (A = {Al, Ga, In}) and α -M₂AB₂ (A = {Si, Ge}), followed by M₂AB₂ and ω -M₂AB₂. The Ti–Al–B and Ti–Si–B systems exhibit the highest number of possible MABs: M₃AB₄, α -M₂AB₂, M₂AB₂, ω -M₂AB₂, M₃AB₃, and MAB, where the last two exhibit the highest E_f , thus are the least likely to form.
 - For M from the group 5 (= V, Nb, Ta), the lowestenergy MABs are M_3AB_4 , α - M_2AB_2 or M_3AB_2 , where the last one only concerns Ta–A–B systems with A = {Si, Ge, In}. Compared to M from the group 4, there are more competing MABs. The MAB phase prototype becomes a competing phase, particularly for A = {Al, Si}. The M_2AB_2 and ω - M_2AB_2 prototypes are competing phases in the V–A–B and Nb–A–B systems for A = {Ga, In}.
 - For M from the group 6 (= Cr, Mo, W), the lowestenergy MABs are M₃AB₄, α-M₂AB₂, M₂AB₂, MAB (Mo–Al–B and W–Al–B systems), α'-M₂AB₂ (W–Si–B and W–Ga–B systems), and M₃AB₃ (W–Ge–B system). While nearly all the here-considered phase prototypes fall within the E_f threshold, some are dynamically unstable.
 - For M from the group 7 (= Mn, Tc, Re), the lowest-energy MABs are ω'-M₂AB₂, M₂AB₂ (Mn–A–B system for A={Al, Si, Ga}), α-M₂AB₂ (Mn–Ge–B system), M₃AB₄ (Mn–In–B system). Mn–Al–B and Re–Al–B exhibit the highest number of competing MABs.

Calculated with respect to energies of the constituting elements (i.e. their chemical potentials), absolute E_f values in Fig. 2 may change under (highly) non-equilibrium synthesis conditions, reflected by changes of the reference chemical potentials (see a case-study of TaN⁶⁴). Consequently, this may alter relative stability order of energetically-close MABs. The actual E_f distribution of all dynamically stable MABs, however, will be less affected by "small" variations of chemical potentials. In particular, a system in which the lowest-energy phase exhibits a "large" E_f separation from competing phases will likely enable single-phase MAB formation (supposing it will not decompose into binary or ternary non-MAB compounds), contrarily to a system with many energetically-close phases. To quantify this intuitive idea, we take inspiration in the EFA (entropy forming ability) descriptor by Curtarolo and co-workers^{65,66} and introduce a *single-phase indicator*, SPI. Considering the E_f distribution of competing MABs in a given M–A–B system, SPI is calculated as

$$SPI(n) = \{ \boldsymbol{\sigma}[spectrum(E_f(n))] \}^{-1}, \qquad (4)$$

where σ is a standard deviation of energies, E_f . A "low" SPI suggests a high propensity to form a single-phase MAB, similar to Curtarolo's "low" EFA pointing towards formation of a single-phase high-entropy ceramic⁶⁵. An example E_f spectra together with the resulting SPI are given in Fig. 3(a,b,c). The SPIs evaluated for all elemental combinations (Fig. 3d) render the following hypotheses:

- Hf and Zr combined with Si or Ge are likely to form single-phase MABs (SPI ≈6–7 (eV/at.)⁻¹), if not decomposed into other non-MAB compounds.
- Contrarily, Re in combination with Si (SPI \approx 98 (eV/at.)⁻¹) or Ge (SPI \approx 56 (eV/at.)⁻¹), and Mn and W in combination with In (SPI of \approx 37 and 45 (eV/at.)⁻¹, respectively) do not provide a suitable basis for stabilisation of single-phase MABs.
- For A=Al—the most typical A element in experimentally reported MABs—there is no extremely high or low propensity to single-phase MABs formation. Examples of M elements yielding relatively "lower" and "higher" SPI are M= {Ti, Cr, Mo, Mn, Tc, Re}, with SPI $\approx 10-13$ (eV/at.)⁻¹, and M= {Zr, Hf, Ta} with $\approx 21-26$ (eV/at.)⁻¹, respectively.

The SPI reflects energetic aspects only (here, zero Kelvin formation energies of dynamically stable MABs). In practice, however, single-phase MAB formation will be driven also by kinetic factors and specific experimental setup (e.g. sputtering from a ternary vs. elemental targets). A simple add-on to the SPI may be considering the volumetric proximity of competing phases based on the V_{per-at} data in Suppl. Fig. S1.

Supposing the MABs' layered character enables a relatively "easy" transformation pathway from one phase prototype to another, the availability of energetically-close phases (intermediate-to-high SPI) with similar volumes as the energetically most preferred phase may actually be beneficial: facilitating transformation toughening during volume-changing mechanical deformation. For example, cubic $Ti_{0.5}Al_{0.5}N$ subject to [001] tension undergoes local lattice transformations to the energetically-close wurtzite structure, thus improving toughness⁶⁷. An additional important condition for the phase transformation may be that the M:A:B ratio remains unchanged.



Figure 2. Trends in the phase stability of MABs, as quantified by the formation energy, E_f (see Eq. (1)). For each (M, A) combination, the black solid lines guide the eye for MABs energetically close to the lowest-energy phase, i.e. within the E_f threshold, $E_f^{\text{thr}} = 0.25$ eV/at. MABs that are above E_f^{thr} , and/or, mechanically, and/or dynamically unstable are depicted in grey. All MABs marked by colour are mechanically and dynamically stable. Trends in the corresponding per-atom volumes, densities, and atomic difference ratios are shown in Suppl. Fig. S1, Suppl. Fig. S2, and Suppl. Fig. S3, respectively.



Figure 3. Prediction of the MABs' propensity to form a single-phase compound, as quantified by the single-phase indicator, SPI, see Eq. (4). (a,b,c) Examples of formation energy (E_f) spectra used to derive SPI. The spectra contain all dynamically stable phases (identified in Fig. 2) for the respective (M, A) combination. (d) The SPI descriptor for all (M, A) combinations. Low SPI values indicate tendency to form as single-phase MAB, whereas high SPIs are a sign of several energetically-close competing MABs. Mind the log scale of the y-axis (SPI).

Our E_f and volumetric analysis points towards Cr₂AlB₂, (3.2c) For the same phase prototype and M from the same Re₂AlB₂, Cr₂SiB₂, W₂SiB₂, and Mn₂SiB₂ as to MAB phases with intermediate SPI $\approx 11-25$ (eV/at.)⁻¹, favouring the 2:1:2 stoichiomtery and exhibiting energetically-close 2:1:2-type phases with volumes by 1%-10% larger (smaller in case of Mn₂SiB₂), thus possibly forming under tensile (compressive) strains.

3.2 Trends in the electronic structure

Our stability predictions revealed in total 317 (meta)stable MABs (see coloured symbols in Fig. 1). Due to various crystal symmetries, chemistry, and elemental composition, however, understanding trends in their mechanical properties may be difficult. To shed light on their most fundamental similarities and differences, we first investigate their electronic density of states (DOS) near the Fermi level.

Fig. 4 presents DOS of selected representative MABs, illustrating general trends observed also for other phase prototypes and (M, A) combinations. The energy range in focus is $\approx [-15,5]$ eV, where 0 corresponds to the Fermi level, E_F . From a qualitative DOS analysis, we infer the following:

- (3.2a) The DOS of all MABs has metallic character and the Fermi level vicinity is dominated by the transition metal d-electrons (Fig. 4a–o), suggesting that the M element significantly influences mechanical properties.
- (3.2b) The most decisive factor for the general shape of DOS is the phase prototype, whereas the E_F position with respect to the nearest peaks is mainly governed by the M element's group (Fig. 4a-l). Exceptions (e.g. Cr₃B₄ in Fig. 4i) may be rationalised by high formation energy of the corresponding phase prototype for given M.

- group in the periodic table (i.e. with the same valence electron concentration), both the shape of DOS and E_F are typically nearly the same (Fig. 4d–f).
- (3.2d) Changing the A element influences the general shape of DOS, however, to a lesser extent than changing the phase prototype (Fig. 4m–o). The relative E_F position with respect to the neighbouring peaks is nearly uninfluenced.

Our results indicate that the main features of DOS near E_F are dictated by the phase prototype, which may be the most natural mean of sorting MABs when searching for trends in mechanical properties. The group of the M element-in other words, the number of M's valence electrons-influences the Fermi level position with respect to the closest DOS minimum or peak, thus, may be a crucial factor for optimisation of mechanical properties. Shifting the E_F for different phase prototypes, however, will likely lead to filling different states and an in-depth analysis (out of our scope) would be necessary to understand how these impact the MABs' mechanical response.

3.3 Stiffness and ductility indicators

This section focuses on predicting trends in mechanical properties of MAB phases via phenomenological elastic-constantsbased descriptors. Specifically, Young's modulus (E), shearto-bulk modulus ratio (G/B), and Cauchy pressure (CP) are used to compare all dynamically stable MAB candidates (all coloured symbols in Fig. 1, comprising 317 MABs) in terms of theoretical stiffness and ductility. Although ductility is a complex property-dictated by structure, density, and mobility of extended crystallographic defects over different length and time scales— C_{ij} -based indicators have served as common



Figure 4. Electronic density of states (DOS) for representative MABs illustrating general DOS shape depending on the phase prototype and elemental composition. The grey-shaded area denotes the total DOS, while the red, blue, and yellow lines are partial contributions from the M, A, and B element (dotted line: s-electrons, dashed line: p-electrons, solid line: d-electrons). The zero energy always denotes the Fermi level (E_F). (a–c) **The role of the group from which M is chosen**, exemplified by the M₂AB₂ phase prototype. The DOS shapes are very similar, while the E_F shifts. (d–f) **The role of the group from which M is chosen**, exemplified by the M₂AB₂ phase prototype. Both the DOS shape and E_F are very similar. (g–i) **The role of the group from which M is chosen**, exemplified by the M₃AB₄ phase prototype. The DOS shape is very similar (slightly differing for the energtically least stable Cr₃AlB₄), while the E_F shifts. (j–l) **The role of the group from which M is chosen** is very similar, while the E_F shifts. (m-l) **The role of the A element**, exemplified by the M₃AB₄ phase prototype. The DOS shape is very similar, while the E_F shifts. (m-l) **The role of the A element**, exemplified by the M₃AB₄ phase prototype. The DOS shape is shift, while the E_F shifts.

trend-givers in the family of refractory ceramics^{34–37,68,69} with reasonably similar crystal and electronic structures.

Due to the non-cubic crystal symmetry and layered architecture, MAB phases should generally exhibit an anisotropic elastic response. The degree of anisotropy can be estimated by the universal anisotropy index, A^{U70} , identically zero for locally isotropic single crystals. In our case, A^U varies between 0.01 (α -Nb₂InB₂) and 6.35 (Ta₃InB₄), where nearly 80% of all MABs exhibit $A^U \le 0.5$ (Suppl. Fig. S8). The most energetically preferred phase for a given (M, A) combination yields $A^U = 0.01-1.43$, comparable to $A^U = 0.01-1.88$ of transition metal diboride ceramics (MB₂, M from the group 4– 7; A^U was evaluated based on data from Ref.⁵³). Interestingly, A^U of the α -M₂AB₂ phase prototype is fairly independent of elemental composition ($A^U = 0.11 \pm 0.14$), while others, e.g., the M₂AB₂ and M₃AB₄ phase prototype, exhibit larger A^U variations ($A^U = 0.54 \pm 0.49$ and $A^U = 0.66 \pm 1.16$, respectively).

In the first step (Fig. 5), we disregard the MABs' elastic anisotropy and evaluate "effective" strength and ductility indicators using the polycrystalline moduli (B, G, E) and averaging the directional Cauchy pressure values,

$$CP_{\text{eff}} = CP^{\perp} + CP_{[1]}^{\parallel} + CP_{[2]}^{\parallel} =$$

= $\frac{C_{12} - C_{66}}{3} + \frac{C_{13} - C_{44}}{3} + \frac{C_{23} - C_{55}}{3},$ (5)

where CP^{\perp} ($CP^{\parallel}_{[1]}, CP^{\parallel}_{[2]}$) are out-of-plane (in-plane) Cauchy pressure, i.e. orthogonal and parallel to the M-B/A layers. The obtained ductility map (CP_{eff} vs. G/B in Fig. 5a) indicates an important role of the M element. The strongest trend observed is a ductility increase for M from the group $4 \rightarrow 5 \rightarrow 6 \rightarrow 7$. Among the most ductile MABs containing common elements (excluding Ga, Ge, In, Mn, Tc) are V₂SiB, Nb₂SiB, Ta₂AlB₂, Ta₃AlB₄, Ta₂SiB, Cr₃AlB₃, Mo₂AlB₂, Mo₂SiB₂, Mo₃AlB₃, Mo₃SiB₃, W₃SiB₂, Re₂AlB₂, and Re-AlB. There are, however, several outliers. For example, Cr₂AlB₂ and MoAlB (M from the group 6) are predicted to be surprisingly brittle ($CP_{eff} < -30$ GPa), while Ti₃GeB₄ and ZrGaB (M from the group 4) would be surprisingly ductile ($CP_{eff} > 30$ GPa). These outliers may be explained by (i) energetic reasons (E_f "high" above that of the lowest-energy phase, e.g., ZrGaB with E_f 0.24 eV/at above E_f of the most stable Zr_3GaB_4), by (ii) differences between the phase prototypes, i.e. different optimal position of the Fermi level (inducing more ductile/brittle response to deformation), by (iii) effects of the A element (recall that In-containing MABs were always the least energetically stable and the least dense), or by (iv) elastic anisotropy. To support the energetic argument (i), all data points in Fig. 5 are scaled based on their E_f difference from the lowest-energy phase for a given (M, A) combination, so that smaller symbol sizes correspond to larger E_f differences.

The so far experimentally reported MABs most often crystallised in the M₃AB₄, M₂AB₂, and MAB type phase, depicted in Fig. 5b–d. Here, Ta₃AlB₄, Ta₂AlB₂, Re₂AlB₂, and ReAlB stand out in terms of theoretical ductility.

Fig. 5e–h shows the relationship between the elastic stiffness and ductility, estimated by the polycrystalline Young's modulus, E, and the shear-to-bulk modulus ratio, G/B, respectively. To prevent failure during mechanical loads, one seeks a compromise between high E and low G/B, providing an atomic-level basis for initially hard but then reasonably plastic response to deformation. For the here-studied MABs, E varies significantly—between 96 GPa (ω -Mo₂GeB₂) and 441 GPa (Cr₃AlB₄)—and seems to be less controlled by the M element than ductility.

Suggested already by low density of In-containing MABs (Section 3.1, Suppl. Fig. S2), their *E* moduli are generally low, 232 ± 50 GPa, where the standard deviation represents values from various M elements and phase prototypes. Al- and Si-containing MABs, in contrast, posses relatively high *E* values,

312±60 GPa. There is eleven MABs with E > 400 GPa. Only one contains a group 4 M element (Ti₃AlB₄) and the top three are Cr₃AlB₄, TaSiB, and VSiB possessing *G/B* of 0.73, 0.80 0.84, respectively, thus illustrating the typical inverse relationship between stiffness and ductility. A combination of relatively high Young's modulus (E > 350 GPa) and low *G/B* ratio (*G/B* < 0.55) is shown by Cr₂SiB₂, Cr₃SiB₄, W₂AlB₂, α -W₂SiB₂, and γ -Re₂GeB₂. Among them, Cr₃SiB₄ is the lowest-energy phase in the Cr–Al–B system, and the other ones are energetically close to their most favourable phases ($\Delta E_f = 0.01-0.05$ eV/at.).

As noted at the beginning of this section, elastic response of MABs is strongly directional. This is illustrated in Fig. 6 presenting two Cauchy pressure and Young's modulus values: in-plane, i.e., parallel to the metal/ceramic layers (denoted by CP^{\parallel} , E^{\parallel}), and out-of-plane, i.e. orthogonal to the metal/ceramic layers (denoted by CP^{\perp}, E^{\perp}). The latter is aligned with the most typical growth direction. According to Fig. 6a, about 20% of all MABs can be seen as strongly Cauchy-pressure anisotropic, with $|CP^{\parallel} - CP^{\perp}| >$ 100 GPa. Interestingly, the ratio of MABs with $CP^{\parallel} > CP^{\perp}$ and $CP^{\parallel} < CP^{\perp}$ is nearly 1:1. Examples of extreme cases include Mn₂SiB₂ and α -Re₂AlB₂ ($CP^{\parallel} - CP^{\perp} > 150$ GPa, indicating superior in-plane ductility), or Ta₂SiB and γ -Mo₂GaB₂ $(CP^{\perp} - CP^{\parallel} > 150 \text{ GPa}, \text{ indicating superior out-of-plane duc-}$ tility). Furthermore, the data show that (i) almost all MABs containing group 4 transition metals exhibit $CP^{\parallel} < CP^{\perp}$, and (ii) the ω' -M₂AB₂, γ -M₂AB₂ and M₂AX prototypes show $CP^{\parallel} \ll CP^{\perp}$ for the group 6 M elements.

Focusing on the most common phase prototypes and (M, A) combinations, the M₃AB₄ (Fig. 6b) and the M₂AB₂ (Fig. 6c) type phases are predicted to be more ductile in-plane, with extreme cases ($CP^{\parallel} \gg CP^{\perp}$) being Nb₃AlB₄, Ta₃AlB₄, Ta₂AlB₂, and Re₂AlB₂. The MAB phase prototype (Fig. 6d) can be seen as rather Cauchy-pressure isotropic.

Concerning Young's moduli, their in-plane and out-of-plane values Fig. 6e–h do not show a simply reversed trend with respect to the directional Cauchy pressures. Besides Ti₃SiB₄, Ti₂SiB₂, and ZrAlB, all MABs containing group 4 transition metals and most MABs containing group 5 transition metals are stiffer in-plane compared to their [001] direction. This is intuitively expected due to relatively weak bonding between the ceramic (M–B) and metallic (A) layers. Similar to Fig. 6a, the ω' -M₂AB₂, γ -M₂AB₂ and M₂AX prototypes tend to cluster for the group 6 M elements and can be seen as outliers with significantly higher out-of-plane stiffness ($E^{\perp} - E^{\parallel} > 150$ GPa).

Among the most common phase prototypes and (M, A) combinations, the M₃AB₄ (Fig. 6f) and the M₂AB₂ (Fig. 6g) type phase typically exhibit $E^{\parallel} > E^{\perp}$. In particular, Nb₃AB₄, Ta₃AB₄, and Re₂AlB₂ yield $E^{\parallel} - E^{\perp} > 100$ GPa. The MAB phase prototype (Fig. 6h) shows small differences between in-plane and out-of-plane Young's moduli, with the most anisotropic MABs being CrAlB, ZrSiB, and the energetically rather unlikely (smaller symbol sizes) TiAlB and VAlB.



Figure 5. Trends in theoretical ductility (a–d) and stiffness (e–h) of MAB phases estimated via elastic-constants-based descriptors: effective Cauchy pressure (CP_{eff} , Eq. 5), polycrystalline shear-to-bulk modulus ratio (G/B), and polycrystalline Young's modulus (E). The dashed lines in (a–d) guide the eye for Pettifor's⁷¹ and Pugh's⁷² semi-empirical ductility criteria (commonly used for ceramics^{34–37,68,69} but originally developed for metals, these criteria should be treated only on a qualitative level). Panels (a) and (e) show results for all stable phases (marked by colour in Fig. 2), while panels (b–c) and (f–h) focus on the most common phase prototypes and elements (excluding Mn, Tc, Ga, Ge, In). The underlying (phase-, M-element-, and A-element-resolved) *B*, *G*, and *E* values for all MABs are shown in Suppl. Fig. S4, Suppl. Fig. S5, and Suppl. Fig. S6, respectively. The corresponding Poisson's ratios are shown in Suppl. Fig. S7.



Figure 6. Trends in theoretical in-plane vs. out-of-plane ductility (a–d) and stiffness (e–h) of MAB phases estimated via elastic-constants-based descriptors: directional Cauchy pressure $(CP_{\text{in-plane}} = CP^{\parallel}, CP_{\text{out-of-plane}} = CP^{\perp})$ and directional Young's modulus $(E_{\text{in-plane}} = E^{\parallel}, E_{\text{out-of-plane}} = E^{\perp})$. The dashed diagonal lines guide the eye for the case of equal in-plane and out-of-plane values. Panels (a) and (e) show results for all stable phases (marked by colour in Fig. 2), while panels (b–c) and (f–h) focus on the most common phase prototypes and elements (excluding Mn, Tc, Ga, Ge, In).

3.4 Suggestions for the most promising MABs

In Fig. 7 we present M–A–B systems suitable for the development of MAB phases with favourable combination of stiffness and ductility. These are identified based on Cauchy pressure and Young's modulus values of all mechanically and dynamically stable MABs, weighted according to their formation energy difference from the energetically most stable phase.

Consequently, the following elemental combinations are proposed:

A = Al and M = {Nb, Mo, W, Mn, (Tc), Re} (Fig. 7a). The most energetically stable compounds—listed in Tab. 1—are Nb₃AlB₄, Mo₂AlB₂, MoAlB, W₂AlB₂, WAlB, Mn₂AlB₂, γ-Re₂AlB₂, and ω'-Re₂AlB₂ (Tab. 1). Bulk WAlB^{9,15}, bulk Mn₂AlB₂^{15,17}, and thin film and bulk MoAlB^{9,14,18–20} have already been synthesised. The experimental Young's modulus of MoAlB¹⁹, *E* = 379 ± 30 GPa, compares well with our DFT value, *E* = 346 GPa (Tab. 1). Furthermore, the here-predicted Mo₂AlB₂ was observed in HRTEM after topochemical deintercalation of Al from the single crystalline MoAlB⁴.

With both Cauchy pressures positive $(CP^{\parallel} \approx 36 \text{ GPa}, CP^{\perp} \approx 16 \text{ GPa})$ and the lowest G/B (≈ 0.53), W₂AlB₂ stands out in terms of theoretical ductility. Mn- and Recontaining MABs exhibit the highest elastic stiffness. Mn₂AlB₂ is significantly stiffer in-plane, $E^{\parallel} \approx 419$ GPa, $E^{\perp} \approx 292$ GPa (comparable to room-temperature experimental value of 243 GPa¹⁷), whereas γ -Re₂AlB₂ is notably more isotropic, $E^{\parallel} \approx 373$ GPa, $E^{\perp} \approx 371$ GPa).

• A = Si and M = {V, Nb, Ta, Cr, Mo, W, Mn, (Tc), (Re)} (Fig. 7b). The most energetically stable compounds are α -V₂SiB₂, V₃SiB₄, α -Nb₂SiB₂, Ta₃SiB₂, α -Ta₂SiB₂, Ta₂SiB, Cr₂SiB₂, Cr₃SiB₄, α -Cr₂SiB₂, α -Mo₂SiB₂, ω' -W₂SiB₂, γ -W₂SiB₂, W₂SiB, α -W₂SiB₂, W₃SiB₃, Mn₂SiB₂, α -Mn₂SiB₂, γ -Mn₂SiB₂, and ω' -Mn₂SiB₂ (Tab. 1). Re exhibits many competing phases.

Contrarily to Al-containing MABs, their Si counterparts are experimentally mostly unexplored. Considering outstanding oxidation properties of Si-alloyed boride ceramics^{73–75}, we envision that also Si-containing MABs will attract attention.

As suggested by Cauchy pressure and Poisson's ratio values in Tab. 1, Si-based MABs are slightly less brittle than Al-based MABs. With the 2:1:2 M:A:B chemistry, W exhibits three energetically- and volumetrically-close phase prototypes ($\Delta E_f = 0.001-0.045 \text{ eV/at.}$, $\Delta V = 0-3.4\%$) providing a basis to optimise mechanical properties. Similarly, Mn offers four energetically-close phases of the 2:1:2 chemistry. The α -Mn₂SiB₂ exhibits the highest ductility indicators among all Si-containing MABs ($CP^{\parallel} \approx 102 \text{ GPa}$, $CP^{\perp} \approx 27 \text{ GPa}$, $G/B \approx 0.4$, $v \approx 0.32$), but rather low Young's moduli (< 300 GPa).

• $A = Ga \text{ and } M = \{V, Cr, W\}$ (Fig. 7c). The most energetically stable compounds are α -V₂GaB₂, V₃GaB₄,

Cr₃GaB₄, α -Cr₂GaB₂, Cr₂GaB₂, ω' -W₂GaB₂, and γ -W₂GaB₂ (Tab. 1). Although no Ga-containing MABs have been reported, several Ga-containing MAX phases (Ti₂GaC, Ti₄GaC₃, Cr₂GaC) have been explored^{76,77}.

The here-suggested Ga-based MABs are significantly Young's-modulus- and Cauchy-pressure anisotropic. For illustration, W-containing MABs show $CP^{\perp} \ge 110$ GPa and $CP^{\parallel} \le -56$ GPa.

A = Ge and M = {V, Mn, (Re)} (Fig. 7d). The most energetically stable compounds are α-V₂GeB₂ and α-Mn₂GeB₂ (Tab. 1). Re exhibits many competing phases. Similar to Ge, also Ge-based MAB phases are currently a theoretical concept. Nonetheless, there are reports on Ge-based MAX-phase thin films (Ti₂GeC, Ti₃GeC₂, Ti₄GeC₃, Cr₂GeC^{78,79}), which may also inspire the development Ge-containing MABs.

The here-suggested Ge-based MABs have generally rather low bulk moduli. The α -Mn₂GeB₂ stand out in terms of theoretical ductility ($CP^{\parallel} \approx 84$ GPa, $CP^{\perp} \approx 45$ GPa, $G/B \approx 0.39$, and $v \approx 0.33$).

4 Summary and conclusions

High-throughput *ab initio* calculations were employed to facilitate rational material selection for the synthesis of novel ternary borides with MAB-phase structures. The most promising MAB candidates were identified based on the predicted phase stability trends, energetics and volumetric proximity of competing MABs, as well as elastic-constants-based indicators of intrinsic stiffness and ductility parallel and normal to the metal/ceramic layers.

The searched chemical and phase space contained all combinations of the group 4–7 transition metals (M elements) and Al, Si, Ga, Ge or In (A elements), with 10 possible phase prototypes for each elemental combination. Representing the 1:1:1, 2:1:1, 2:1:2, 3:1:2, 3:1:3, and 3:1:4 M:A:B ratios, the prototypes included experimentally known MAB and MAX phases, or were inspired by typical transition metal (di)boride structures interlayered with an A layer. The main predictions are as follows:

The MABs' formation energy typically increases (indicating lower chemical stability) for M from the group 4→5→6→7. The group of M also most notably influences the preferred phase prototype and the number of energetically- and volumetrically-close MABs, which is the highest for the group 5–6 transition metals. Compared to M, the A element's effect is lower, most often decreasing stability as Al→Si→Ga→Ge→In, where Incontaining MABs are also the least dense.

[Supporting data and discussion in Sec. 3.1]

 Consistently with qualitative analysis of the electronic density of states, the M element significantly influences elastic properties. The strongest trend observed is a



Figure 7. Suggestion of suitable M–A–B systems for the development of MAB phases with favourable combination of stiffness and ductility. The relative stiffness (ductility) indicator is calculated as a weighted average of the polycrystalline Young's moduli, *E*, (effective Cauchy pressures, *CP*_{eff}) of all stable MABs in the respective M–A–B system (identified in Fig. 2). The weights are based on the formation energy difference from the lowest-energy phase—having a weight of 1—and the values are then normalised with respect to the global maxima (the Mn–Si–B and Re–Si–B system for ductility and stiffness, respectively). The symbol size scales with the *single-phase indicator* (SPI, Eq. (4)): systems that tend to form single-phase MABs are depicted by larger symbols, while systems with energetically-close competing phases are depicted by smaller symbols. The dashed lines guide guide the eye for top 60%-ranking material systems (top-right corner).

ductility increase for M from the group $4 \rightarrow 5 \rightarrow 6 \rightarrow 7$. Aland Si-containing MABs typically possess the highest Young's moduli. The energetically most stable phases tend to show the lowest degree of elastic anisotropy, comparable to that of transition metal diborides.

[Supporting data and discussion in Sec. 3.2 and 3.3]

3. The suggested most promising MAB candidates combine group 5–6 transition metals and Al or Si, most often with the 2:1:2 chemistry. Based on the Cauchy pressures and Poisson's ratio, Si-based MABs are predicted to be slightly less brittle. Among them, W₂SiB₂ and Mn₂SiB₂ exhibit energetically- and volumetrically-close phases of the same chemistry, possibly facilitating transformation plasticity upon loading.

[Supporting data and discussion in Sec. 3.4]

In projection, our study may guide experimental development of laminated borides with optimised structure–property relationships. Additionally, the here-produced coherent and accurate *ab initio* dataset can serve to train machine-learning models (e.g., for formation energy and elastic constants predictions) or to fit machine-learning interatomic potentials. Possible next steps on the computational side include (i) calculations of decomposition energies with respect to non-MAB compounds (e.g. intermetallics), (ii) the impact of point defects on phase stability and elastic properties, (iii) in-depth studies on Cr_2SiB_2 and Mn_2SiB_2 (which we suggested as promising but treated as non-magnetic), and (iv) transformation pathways between specific prototypes (e.g. for various 2:1:2 types, to assess the possibility of transformation plasticity under mechanical loads as suggested here).

Table 1. Properties of the most energetically favourable MABs for promising (M, A) combinations (as identified in Fig. 7). The columns "M", "A", "Phase", ΔE_f , and ΔV specify the elements, M and A, the phase prototype, the formation energy and volume difference from the most stable phase in the respective M–A–B system (phases with $\Delta E_f < 0.05 \text{ eV/at.}$ are shown). Furthermore, the universal anisotropy index (A^{U70}), the polycrystalline bulk, shear, and Young's modulus (B, G, E), the in-plane and out-of-plane Young's modulus (E^{\parallel} , E^{\perp}), the effective Cauchy pressure (CP_{eff}), the in-plane and out-of-plane Cauchy pressure ($CP^{\parallel}, CP^{\perp}$), the B/G ratio, and the Poisson's ratio (ν) are presented.

М	А	Phase	ΔE_f	ΔV	A^{U}	В	G	Ε	E^{\parallel}	E^{\perp}	<i>CP</i> _{eff}	CP^{\parallel}	CP^{\perp}	G/B	v
			[eV/at.]	[%]		[GPa]	[GPa]	[GPa]	[GPa]	[GPa]	[GPa]	[GPa]	[GPa]	,	
Nb	Al	M ₃ AB ₄	0	0	0.21	227	127	322	351	228	8	37	-49	0.56	0.26
	Al	α -M ₂ AB ₂	0.011	-15.6	0.03	182	130	315	297	268	-36	-42	-23	0.71	0.21
Мо	Al	M_2AB_2	0	0	0.06	237	134	338	379	284	13	25	-9	0.56	0.26
	Al	MAB	0.006	-4.6	0.16	211	141	346	276	252	-32	-45	-6	0.67	0.23
W	Al	MAB	0	0	0.18	229	146	361	269	276	-23	-41	12	0.64	0.24
	Al	M_2AB_2	0.02	4	0.06	260	138	352	375	287	30	36	16	0.53	0.27
Mn	Al	M_2AB_2	0	0	0.09	237	166	404	419	292	-45	-17	-102	0.70	0.22
Re	Al	γ -M ₂ AB ₂	0	0	0.02	255	162	402	373	371	-17	-23	-5	0.64	0.24
	Al	ω' -M ₂ AB ₂	0.002	0	0.02	253	159	394	373	362	-12	-19	1	0.63	0.24
V	Si	α -M ₂ AB ₂	0	0	0.09	218	156	379	338	310	-48	-70	-4	0.72	0.21
	Si	M_3AB_4	0.003	12.1	0.26	256	136	346	390	448	18	50	-44	0.53	0.28
Nb	Si	α -M ₂ AB ₂	0	0	0.23	223	136	339	268	279	-15	-45	45	0.61	0.25
Та	Si	M_3AX_2	0	0	0.36	217	115	294	216	211	10	-15	60	0.53	0.27
	Si	α -M ₂ AB ₂	0.006	12	0.36	239	133	336	243	297	0	-43	87	0.56	0.27
	Si	M_2AX	0.044	-5.5	0.92	205	89	233	131	206	27	-23	129	0.43	0.31
Cr	Si	M_2AB_2	0	0	0.15	269	143	365	402	472	23	52	-32	0.53	0.27
	Si	M_3AB_4	0.022	6	0.13	279	151	383	424	478	22	45	-23	0.54	0.27
	Si	α -M ₂ AB ₂	0.045	-7.1	0.11	237	152	375	351	256	-22	-27	-14	0.64	0.24
Мо	Si	α -M ₂ AB ₂	0	0	0.09	253	147	369	324	296	4	$^{-8}$	27	0.58	0.26
W	Si	ω' -M ₂ AB ₂	0	0	0.32	264	151	381	284	474	-3	-51	94	0.57	0.26
	Si	γ -M ₂ AB ₂	0.001	0	0.37	264	147	373	255	486	1	-54	111	0.56	0.26
	Si	M_2AX	0.038	-13.3	0.62	247	128	328	223	171	6	-15	49	0.52	0.28
	Si	α -M ₂ AB ₂	0.045	3.4	0.09	273	147	373	321	318	24	11	49	0.54	0.27
	Si	M_3AB_3	0.049	-5.1	0.25	213	114	290	304	259	12	-1	39	0.54	0.27
Mn	Si	M_2AB_2	0	0	0.26	282	122	320	369	281	68	123	-42	0.43	0.31
	Si	α -M ₂ AB ₂	0.033	-8.7	0.11	237	94	249	292	250	77	102	27	0.40	0.32
	Si	γ -M ₂ AB ₂	0.045	-9.6	0.14	237	158	388	306	366	-32	-49	0	0.67	0.23
	Si	$\omega' - M_2 AB_2$	0.048	-9.6	0.2	236	148	366	284	316	-19	-35	13	0.63	0.24
V	Ga	α -M ₂ AB ₂	0	0	0.02	183	146	346	367	295	-61	-56	-70	0.8	0.18
	Ga	M_3AB_4	0.011	13.5	0.14	223	143	353	387	261	-20	10	-82	0.64	0.24
Cr	Ga	M_3AB_4	0	0	0.09	243	132	335	398	314	20	42	-22	0.54	0.27
	Ga	α -M ₂ AB ₂	0.028	-14.9	0.05	202	148	357	381	265	-47	-33	-74	0.73	0.2
	Ga	M_2AB_2	0.032	_9	0.15	224	119	304	372	268	20	47	-34	0.53	0.27
w	Ga	$\omega' - M_2 AB_2$	0	0	0.24	233	131	331	255	410	3	-56	121	0.56	0.26
	Ga	γ -M ₂ AB ₂	0	0.1	0.23	234	135	339	255	411	-2	-59	110	0.58	0.26
V	Ge	α -M ₂ AB ₂	0	0	0.05	204	144	349	328	289	-38	-55	-4	0.70	0.22
Mn	Ge	α -M ₂ AB ₂	0	0	0.17	218	85	226	283	259	71	84	45	0.39	0.33
	Ge	M_3AB_3	0.048	-1.7	0.46	169	89	226	301	192	8	-3	29	0.53	0.28

CRediT authorship contribution statement

NK: Conceptualisation, Data curation, Formal analysis, Investigation, Methodology, Visualisation, Writing – original draft. LH: Resources, Writing – review & editing. PHM: Resources, Writing – review & editing. DGS: Conceptualisation, Methodology, Resources, Writing – review & editing.

Declaration of Competing Interests

The authors declare no competing interests.

Data Availability

The data presented in this study are available from the corresponding author upon reasonable request.

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SUPPLEMENTARY DATA

- Supplementary figures Fig. S1, Fig. S2, and Fig. S3 complement the discussion of stability trends in Section 3.1 of the main text.
- Supplementary figures Fig. S4, Fig. S5, Fig. S6, Fig. S7, and Fig. S8 complement the discussion of mechanical properties in Section 3.3 of the main text.



Figure S1. Trends in per-atom volume, $V_{\text{per-at.}}$, for MABs depicted in Fig. 1 in the main text. MABs lying above the E_f threshold $(E_f^{\text{thr}} = 0.25 \text{ eV/at}, \text{ described in the main text})$, and/or, mechanically, and/or dynamically unstable MABs are marked by grey colour. All MABs marked by colour are mechanically and dynamically stable. The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.



Figure S2. Trends in density, ρ , for MABs depicted in Fig. 1 in the main text. Denoting *V* volume, the density is calculated as $\rho = m/V$, with $m = (m_M n_M + m_A n_A + m_B n_B)/N_A$, where m_i and n_i are the mass and number of atoms of element type *i* (*i* = {M, A, B}), respectively, and N_A is the Avogadro number. MABs lying above the E_f threshold ($E_f^{\text{thr}} = 0.25$ eV/at, described in the main text), and/or, mechanically, and/or dynamically unstable MABs are marked by grey colour. All MABs marked by colour are mechanically and dynamically stable. The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.



Figure S3. Trends in atomic difference ratio (alternatively called the "size factor"), Δr , for MABs depicted in Fig. 1 in the main text. Following Zhang et al.⁸⁰, Δr is calculated as $\Delta r = \frac{|r_M - r_A|}{r_M}$, where $r_M(r_A)$ represent atomic radius of the M (A) element in a MAB phase. From the definition, Δr , is the same irrespective of the phase prototype, therefore, all points for a given (M, A) combination overlap.



Figure S4. Polycrystalline bulk modulus, *B*, calculated for all MABs fulfilling all stability criteria (E_f "close" above that of the lowest-energy phase, mechanical and dynamical stability). The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.



Figure S5. Polycrystalline shear modulus, *G*, calculated for all MABs fulfilling our stability criteria (E_f "close" above that of the lowest-energy phase, mechanical and dynamical stability). The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.



Figure S6. Polycrystalline Young's modulus, E, calculated for all MABs fulfilling our stability criteria (E_f "close" above that of the lowest-energy phase, mechanical and dynamical stability). The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.



Figure S7. Polycrystalline Poisson's ratio, v, calculated for all MABs fulfilling our stability criteria (E_f "close" above that of the lowest-energy phase, mechanical and dynamical stability). The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.



Figure S8. Universal anisotropy index, A^U calculated for all MABs fulfilling our stability criteria (E_f "close" above that of the lowest-energy phase, mechanical and dynamical stability). The A^U is calculated as $A^U = 5 \frac{G^V}{G^R} - \frac{B^V}{B^R} - 6$ (Eq. 9 in Ref.⁷⁰), where G and B are the shear and bulk moduli and the upper indexes, V and R, denote the Voigt and Reuss estimates. The symbol sizes scale with energetic stability quantified by the E_f difference from the lowest- E_f phase for a given (M, A) combination.